

SBR10U40CT SBR10U40CTF SBR10U40CTI SBR10U40CTB

Super Barrier Rectifier TM

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

Major ratings and characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular Waveform	10	Α
V_{RRM}	40	٧
V _F @5A, Tj=125 ^O C	0.35	V, typ
Tj (operating/storage)	-65 to 150	°C

Device optimized for low forward voltage drop to maximize efficiency in Power Supply applications

ELECTRICAL:

- * Ultra-Low Forward Voltage Drop
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, fast switching capability
- * 150°C Operating Junction Temperature

MECHANICAL:

* Molded Plastic TO-220AB, TO-262, TO-263, and ITO-220 packages

Case Styles					
SBR10U40CT	SBR10U40CTF	SBR10U40CTI	SBR10U40CTB		
			The state of the s		
2 Common 3 Anode	2 Common 3 Anode 3 Anode	2 Common Cathode 3 Anode	2 Common Cathode Anode		
TO-220AB	ITO-220	TO-262	TO-263		



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(at 25°C unless otherwise specified)	1			
	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V _{RM} V _{RWM} V _{RRM}	40		Volts
Average Rectified Forward Current (Rated V _R -20Khz Square Wave) - 50% duty cycle	Io	10		Amps
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	150		Amps
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	3		Amps
Instantaneous Forward Voltage (per leg) $I_F = 5A$; $T_J = 25^{\circ}C$ $I_F = 10A$; $T_J = 25^{\circ}C$ $I_F = 5A$; $T_J = 125^{\circ}C$	V _F	Typ 	Max 0.44 0.52 0.38	Volts
Maximum Instantaneous Reverse Current at Rated V_{RM} $T_{\text{J}} = 25^{\circ}\text{C}$ $T_{\text{J}} = 125^{\circ}\text{C}$	I _R .	Тур 	Max 0.5 100	mA mA
Maximum Rate of Voltage Change (at Rated V _R)	dv/dt	10,000		V/uS
Maximum Thermal Resistance JC (per leg) Package = TO-220AB, TO-262, & TO-263 Package = ITO-220	R⊕ _{JC}	2 4		°C/W

NOTE: Dice are available for customer applications.

Operating and Storage Junction Temperature

 T_J

-65 to +150

οС

^{*} Pulse width < 300 uS, Duty cycle < 2%



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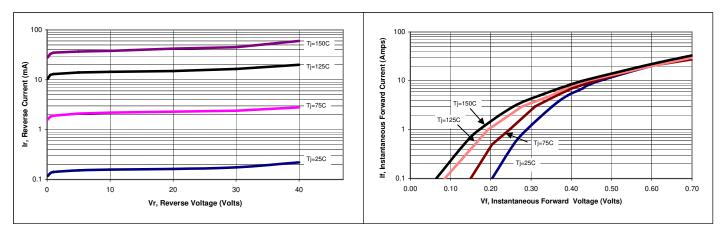


Figure 1: Typical Reverse Current

Figure 2: Typical Forward Voltage

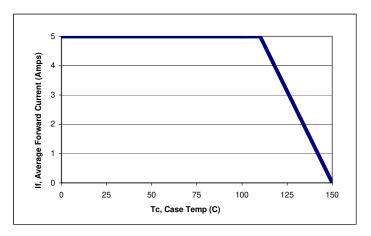
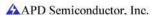


Figure 3: Current Derating, Case

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